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IN THE CLAIMS:

Please amend claims as follows.

1. (currently amended) A tuneable phase shifter and/or attenuator comprising a waveguide having a channel <u>defined by internal walls of the waveguide</u> and a piece of photo-responsive material (18) disposed within the waveguide <u>and having an outside surface directly</u> along [[an]] <u>one of the internal walls</u> of said channel, a light source disposed outside the waveguide to emit light through an aperture (30) of said internal wall to impinge on at least part of [[an]] <u>the</u> outside surface of said piece of photo-responsive material (18).

- 2. (currently amended) The tuneable phase shifter and/or attenuator as in claim 1, wherein the photo-responsive material (18) is a photo-conductive material, e.g. Si, GaAs or Ge.
- 3. (currently amended) The tuneable phase shifter and/or attenuator as in claim 1 wherein at least the surface of the piece of photo-responsive material facing the aperture is pacified by oxidation.
- 4. (original) The tuneable phase shifter and/or attenuator as in claim 3, wherein at least the surface of the piece of photo-responsive material facing the aperture has a coating of an epoxy resin.
- 5. (currently amended) The tuneable phase shifter and/or attenuator as in claim 1, wherein at least part of the surface of the piece of photoresponsive material facing the aperture is covered with strips of reflective elements to avoid radiation inside the wavelength to be lost outside.
- 6. (original) The tuneable phase shifter and/or attenuator as in claim 5, wherein said strips form a grid.
- 7. (currently amended) A tuneable phase shifter and/or attenuator comprising a waveguide having a channel <u>defined by internal walls of the waveguide</u>

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and a piece of photo-responsive material disposed within the waveguide and spaced from an internal wall of said channel, and a light source to emit light to impinge on at least part of a surface of said piece of photo-responsive material, characterized in that the photo-responsive material is spaced from an internal wall of said channel and in that the light source [[being]] is adjustable to generate in the piece of photo-responsive material a carrier concentration between 10¹² cm⁻³ and 10¹⁶ cm⁻³, to modify the real and imaginary part of the dielectric constant of the photo-responsive material whereby at least one mode is generated that has part of [[its]] a field of said mode inside the piece of photo-responsive material and another part of [[its]] the field in the waveguide whereby a phase shifter and/or attenuator that is dependant on the light illumination is generated over a frequency range.

- 8. (original) A tuneable phase shifter and/or attenuator as in claim 7, wherein said carrier concentration is between 10^{14} cm⁻³ and 10^{16} cm⁻³.
- 9. (currently amended) A tuneable phase shifter and/or attenuator as in claim 7, wherein [[a]] said mode is of a first type that has a field intensity inside the photo-responsive material layer that is small relative to the field in the channel outside the photo-responsive material.
- 10. (original) A tuneable phase shifter and/or attenuator as in claim 9, wherein said mode of a first type is TE_{20} .
- 11. (currently amended) A tuneable phase shifter and/or attenuator as in claim 7, wherein [[a]] said mode is of a second type that has a field intensity inside the photo-responsive material that is high relative to the field in the channel outside the photo-responsive material.
- 12. (currently amended) A tuneable phase shifter and/or attenuator as in claim [[7]] $\underline{11}$ wherein [[a]] said mode of the second type is TE_{10} or TE_{11} .

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13. (currently amended) A tuneable phase shifter and/or attenuator as in claim [[11]] 12, wherein the intensity of the light source is adjustable to place at least one of said modes of the second type in a cut-off state.

- 14. (previously presented) A tuneable phase shifter and/or attenuator as in claim 1, wherein the illumination of the piece of photo-responsive material is carried out at an angle such that total internal reflection occurs.
- 15. (new) The tuneable phase shifter and/or attenuator of claim 2, wherein photo-conductive material is one of Si, GaAs or Ge.
- 16. (new) The tuneable phase shifter and/or attenuator of claim of claim 1, wherein the light source is adjustable to generate in said piece of photoresponsive material (18) a carrier concentration between 10^{18} cm⁻³ and 10^{21} cm⁻³.